TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSⅥ-H)

# TPC8047-H

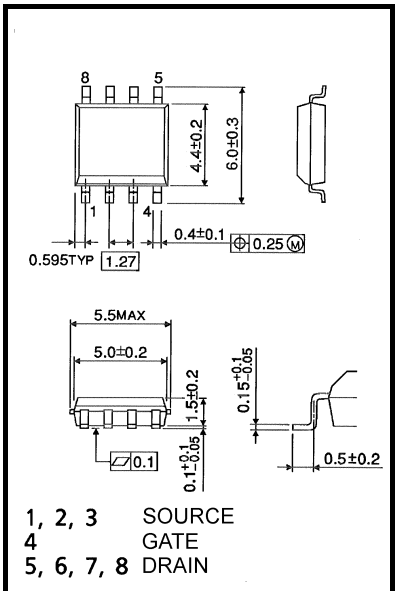
Switching Regulator Applications

Motor Drive Applications

DC-DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: $Q_{SW}$ = 11 nC (typ.)
- Low drain-source ON-resistance:
  $R_{DS\ (ON)}$ = 5.1 mΩ (typ.)
- High forward transfer admittance: $|Y_{fs}|$ = 62 S (typ.)
- Low leakage current: $I_{DSS}$ = 10 μA (max) ($V_{DS}$ = 40 V)
- Enhancement mode: $V_{th}$ = 1.3 to 2.3 V ($V_{DS}$ = 10 V, $I_D$ = 0.5 mA)

Unit: mm



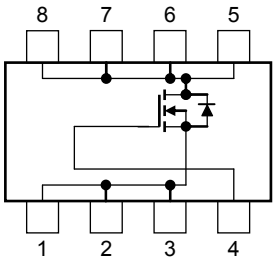

| | |
|---|---|
| JEDEC | — |
| JEITA | — |
| TOSHIBA | 2-6J1B |

Weight: 0.085g (typ.)

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | Symbol | Rating | Unit |
|---|---|---|---|---|
| Drain-source voltage | | $V_{DSS}$ | 40 | V |
| Drain-gate voltage ($R_{GS}$ = 20 kΩ) | | $V_{DGR}$ | 40 | V |
| Gate-source voltage | | $V_{GSS}$ | ±20 | V |
| Drain current | DC (Note 1) | $I_D$ | 16 | A |
| | Pulsed (Note 1) | $I_{DP}$ | 64 | |
| Drain power dissipation (t = 10 s) (Note 2a) | | $P_D$ | 1.9 | W |
| Drain power dissipation (t = 10 s) (Note 2b) | | $P_D$ | 1.0 | W |
| Single-pulse avalanche energy (Note 3) | | $E_{AS}$ | 119 | mJ |
| Avalanche current | | $I_{AR}$ | 16 | A |
| Repetitive avalanche energy (Tc = 25°C) (Note 4) | | $E_{AR}$ | 0.10 | mJ |
| Channel temperature | | $T_{ch}$ | 150 | °C |
| Storage temperature range | | $T_{stg}$ | −55 to 150 | °C |

## Circuit Configuration




Note: For Notes 1 to 4, refer to the next page.

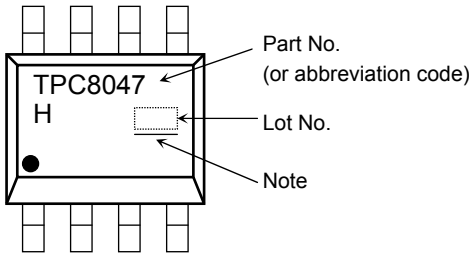
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

## Thermal Characteristics

| Characteristic | Symbol | Max | Unit |
|---|---|---|---|
| Thermal resistance, channel to ambient (t = 10 s) (Note 2a) | $R_{th\ (ch\text{-}a)}$ | 65.8 | °C/W |
| Thermal resistance, channel to ambient (t = 10 s) (Note 2b) | $R_{th\ (ch\text{-}a)}$ | 125 | °C/W |

## Marking (Note 5)

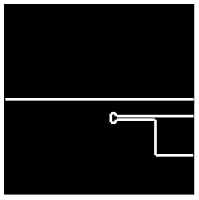



Note : A line under a Lot No. identifies the indication of product Labels
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

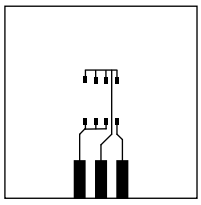
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

(a)



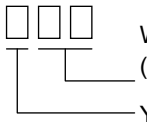
FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

(b)

Note 3: $V_{DD}$ = 24 V, $T_{ch}$ = 25°C (initial), L = 500 μH, $R_G$ = 25 Ω, $I_{AR}$ = 16 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

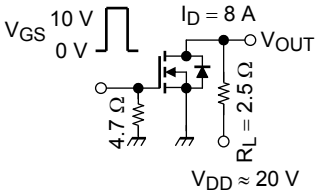
Note 5: * Weekly code: (Three digits)



Week of manufacture
(01 for the first week of the year, continuing up to 52 or 53)

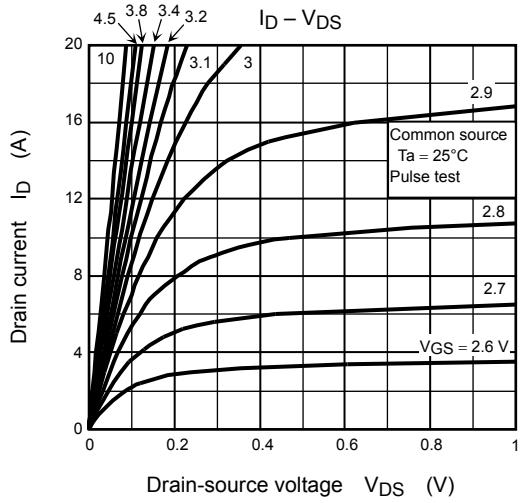
Year of manufacture
(The last digit of the year)

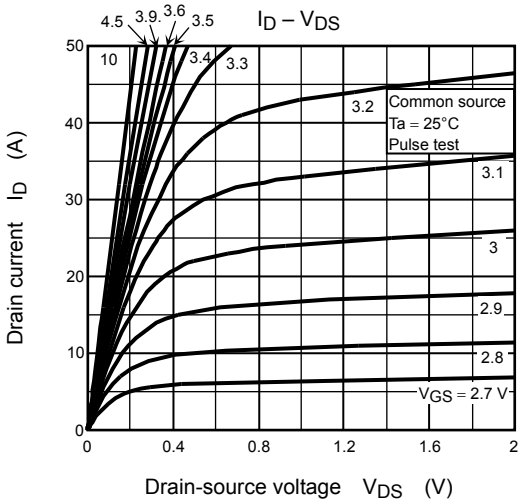
## Electrical Characteristics (Ta = 25°C)

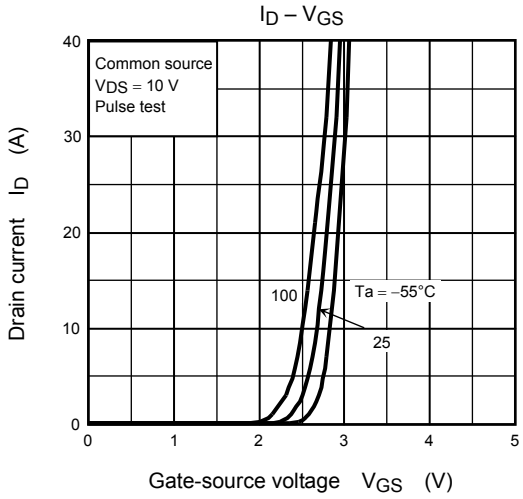
| Characteristic | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|---|
| Gate leakage current | | $I_{GSS}$ | $V_{GS}$ = ±20 V, $V_{DS}$ = 0 V | — | — | ±100 | nA |
| Drain cutoff current | | $I_{DSS}$ | $V_{DS}$ = 40 V, $V_{GS}$ = 0 V | — | — | 10 | μA |
| Drain-source breakdown voltage | | $V_{(BR)\ DSS}$ | $I_D$ = 10 mA, $V_{GS}$ = 0 V | 40 | — | — | V |
| | | $V_{(BR)\ DSX}$ | $I_D$ = 10 mA, $V_{GS}$ = −20 V | 25 | — | — | |
| Gate threshold voltage | | $V_{th}$ | $V_{DS}$ = 10 V, $I_D$ = 0.5 mA | 1.3 | — | 2.3 | V |
| Drain-source ON-resistance | | $R_{DS\ (ON)}$ | $V_{GS}$ = 4.5 V, $I_D$ = 8 A | — | 6.3 | 8.8 | mΩ |
| | | | $V_{GS}$ = 10 V, $I_D$ = 8 A | — | 5.1 | 7.6 | |
| Forward transfer admittance | | $\|Y_{fs}\|$ | $V_{DS}$ = 10 V, $I_D$ = 8 A | 31 | 62 | — | S |
| Input capacitance | | $C_{iss}$ | $V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 1 MHz | — | 2590 | 3365 | pF |
| Reverse transfer capacitance | | $C_{rss}$ | | — | 135 | 200 | |
| Output capacitance | | $C_{oss}$ | | — | 440 | — | |
| Gate resistance | | rg | $V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 1 MHz | — | 1.0 | 1.5 | Ω |
| Switching time | Rise time | $t_r$ |   Duty ≤ 1%, $t_w$ = 10 μs | — | 3.4 | — | ns |
| | Turn-on time | $t_{on}$ | | — | 12 | — | |
| | Fall time | $t_f$ | | — | 8.0 | — | |
| | Turn-off time | $t_{off}$ | | — | 43 | — | |
| Total gate charge (gate-source plus gate-drain) | | $Q_g$ | $V_{DD}$ ≈ 32 V, $V_{GS}$ = 10 V, $I_D$ = 16 A | — | 43 | — | nC |
| | | | $V_{DD}$ ≈ 32 V, $V_{GS}$ = 5 V, $I_D$ = 16 A | — | 23 | — | |
| Gate-source charge 1 | | $Q_{gs1}$ | $V_{DD}$ ≈ 32 V, $V_{GS}$ = 10 V, $I_D$ = 16 A | — | 7.4 | — | |
| Gate-drain (“Miller”) charge | | $Q_{gd}$ | | — | 7.2 | — | |
| Gate switch charge | | $Q_{SW}$ | | — | 11 | — | |

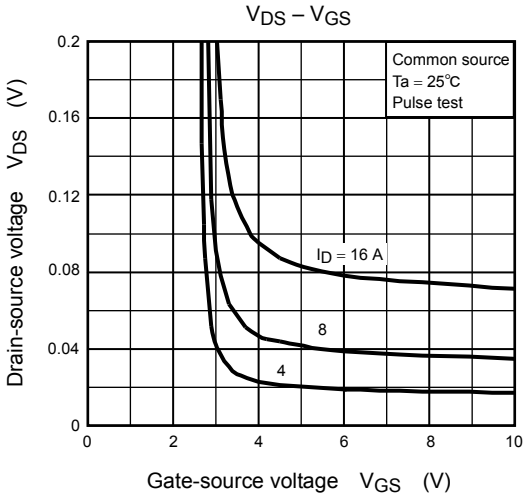
## Source-Drain Ratings and Characteristics (Ta = 25°C)

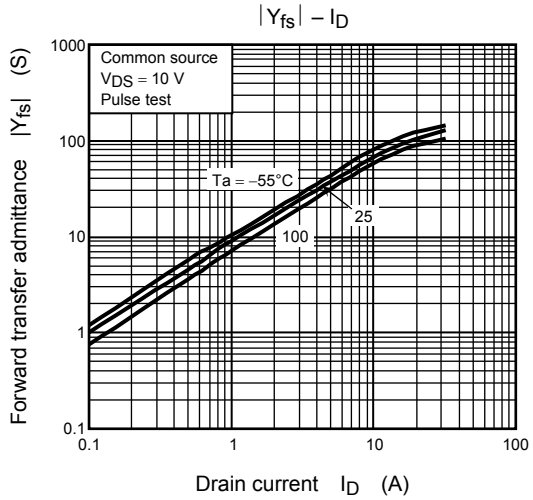
| Characteristic | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|---|
| Peak forward current | Pulse (Note 1) | $I_{FP}$ | — | — | — | 64 | A |
| Forward voltage (diode) | | $V_{DSF}$ | $I_{DR}$ = 16 A, $V_{GS}$ = 0 V | — | — | −1.2 | V |

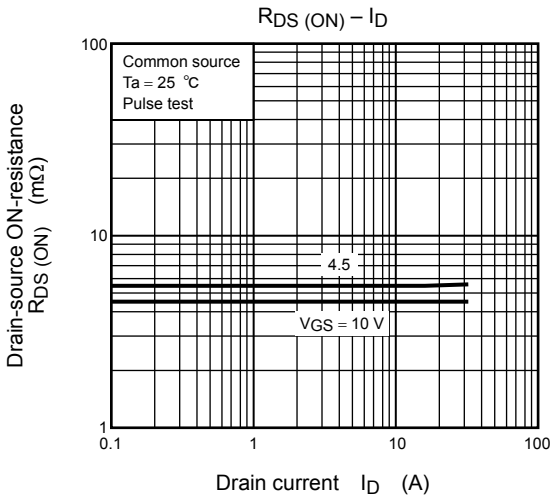

$I_D - V_{DS}$
4.5
3.8
3.4
3.2
10
3.1
3
2.9
2.8
2.7
$V_{GS}$ = 2.6 V
Common source
Ta = 25°C
Pulse test
Drain current $I_D$ (A)
Drain-source voltage $V_{DS}$ (V)


$I_D - V_{DS}$
4.5
3.9
3.6
3.5
10
3.4
3.3
3.2
3.1
3
2.9
2.8
$V_{GS}$ = 2.7 V
Common source
Ta = 25°C
Pulse test
Drain current $I_D$ (A)
Drain-source voltage $V_{DS}$ (V)

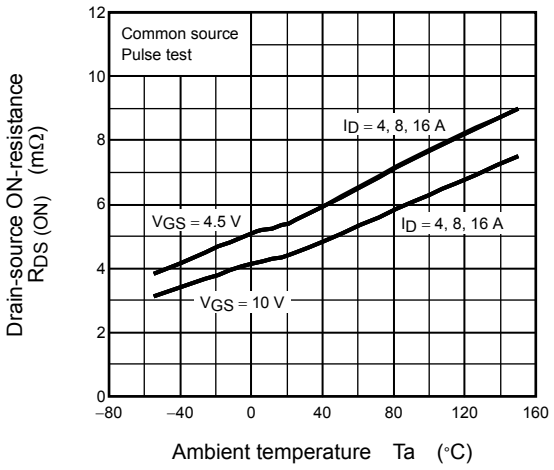

$I_D - V_{GS}$
Common source
$V_{DS}$ = 10 V
Pulse test
100
Ta = −55°C
25
Drain current $I_D$ (A)
Gate-source voltage $V_{GS}$ (V)


$V_{DS} - V_{GS}$
Common source
Ta = 25°C
Pulse test
$I_D$ = 16 A
8
4
Drain-source voltage $V_{DS}$ (V)
Gate-source voltage $V_{GS}$ (V)

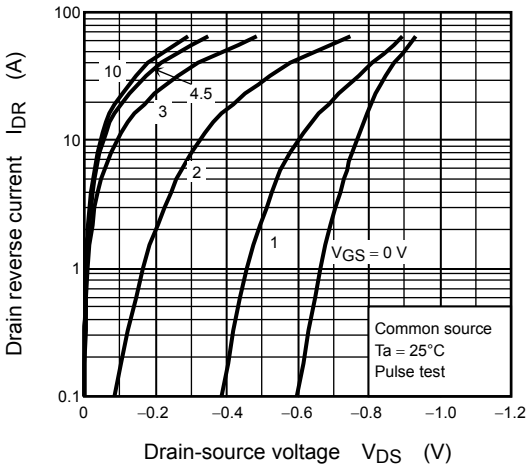

$|Y_{fs}| - I_D$
Common source
$V_{DS}$ = 10 V
Pulse test
Ta = −55°C
25
100
Forward transfer admittance $|Y_{fs}|$ (S)
Drain current $I_D$ (A)


$R_{DS\ (ON)} - I_D$
Common source
Ta = 25 °C
Pulse test
4.5
$V_{GS}$ = 10 V
Drain-source ON-resistance $R_{DS\ (ON)}$ (mΩ)
Drain current $I_D$ (A)

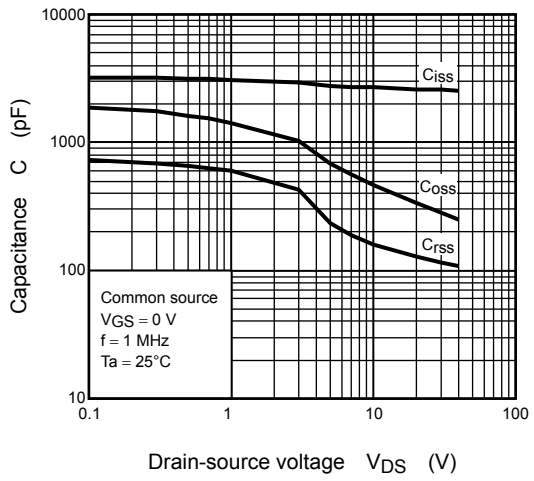
$R_{DS\ (ON)}$ – Ta



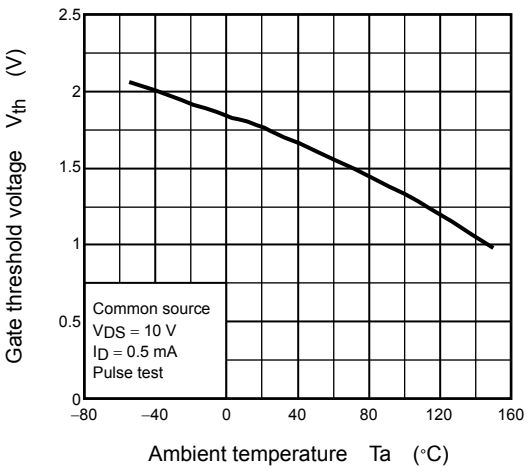

$I_{DR}$ – $V_{DS}$



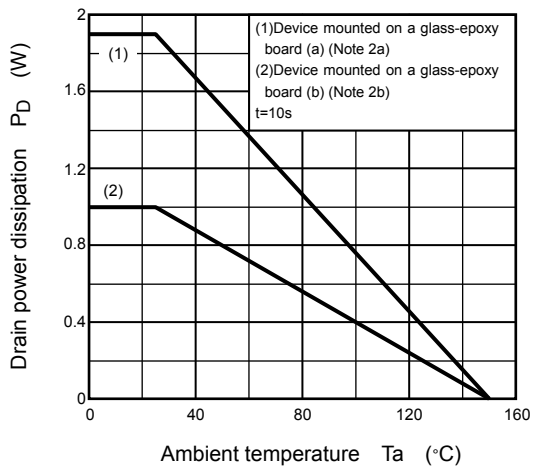

Capacitance – $V_{DS}$



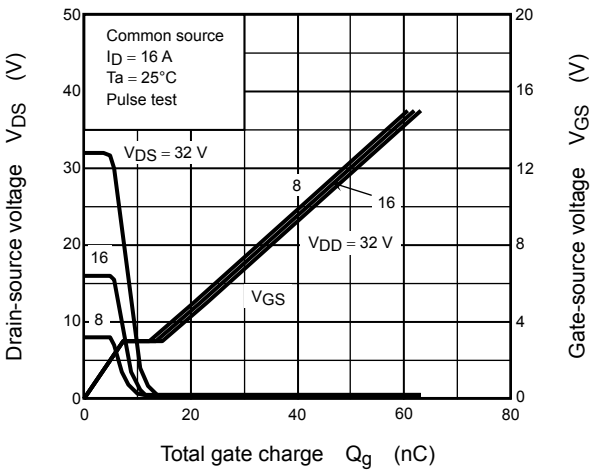

$V_{th}$ – Ta

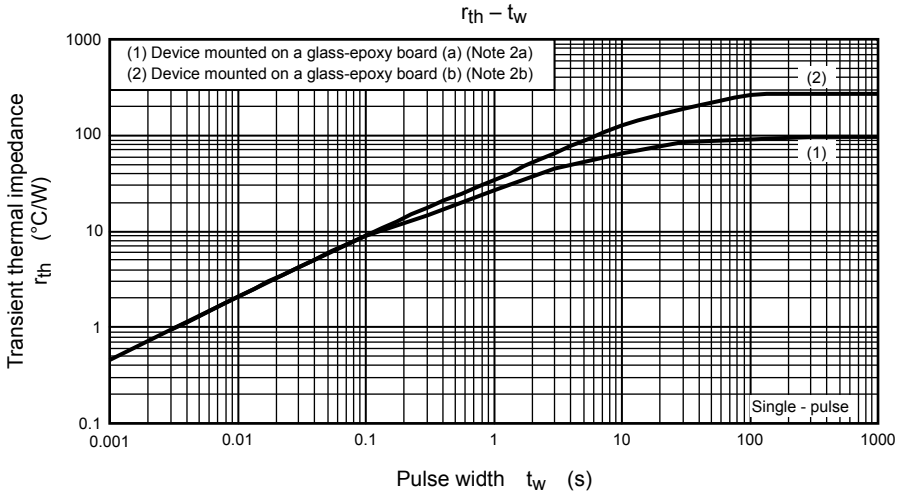


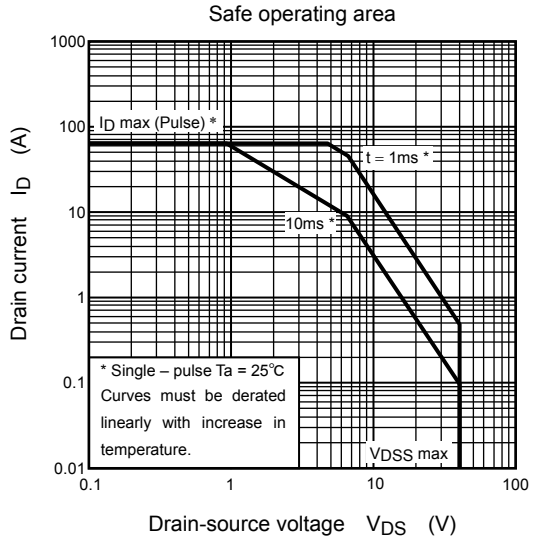

$P_D$ – Ta




Dynamic input/output characteristics




$r_{th} - t_w$
(1) Device mounted on a glass-epoxy board (a) (Note 2a)
(2) Device mounted on a glass-epoxy board (b) (Note 2b)
(2)
(1)
Single - pulse
Transient thermal impedance $r_{th}$ (°C/W)
1000
100
10
1
0.1
0.001
0.01
0.1
1
10
100
1000
Pulse width $t_w$ (s)


Safe operating area
$I_D$ max (Pulse) *
t = 1ms *
10ms *
* Single – pulse Ta = 25°C
Curves must be derated linearly with increase in temperature.
$V_{DSS}$ max
Drain current $I_D$ (A)
1000
100
10
1
0.1
0.01
0.1
1
10
100
Drain-source voltage $V_{DS}$ (V)

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